UNISONIC TECHNOLOGIES CO., LTD

2N80 **Power MOSFET**

2.4A, 800V N-CHANNEL **POWER MOSFET**

DESCRIPTION

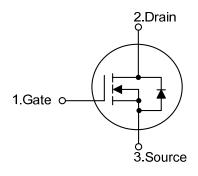
The UTC 2N80 is an N-channel mode power MOSFET using UTC's advanced technology to provide costumers planar stripe and DMOS technology. This technology is specialized in allowing a minimum on-state resistance and superior switching performance. It also can withstand high energy pulse in the avalanche and commutation mode.

The UTC 2N80 is universally applied in high efficiency switch mode power supply.

FEATURES

- * $R_{DS(on)}$ < 6.3 Ω @ V_{GS} =10V, I_{D} =1.2A
- * High switching speed

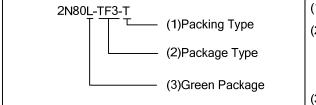
SYMBOL



ORDERING INFORMATION

Ordering Number		Daakaga	Pin Assignment			Packing	
Lead Free	Halogen Free	Package	1	2	3	i acking	
2N80L-TA3-T	2N80G-TA3-T	TO-220	G	D	S	Tube	
2N80L-TF1-T	2N80G-TF1-T	TO-220F1	G	D	S	Tube	
2N80L-TF2-T	2N80G-TF2-T	TO-220F2	G	D	S	Tube	
2N80L-TF3-T	2N80G-TF3-T	TO-220F	G	D	S	Tube	
2N80L-TM3-R	2N80G-TM3-R	TO-251	G	D	S	Tube	
2N80L-TN3-R	2N80G-TN3-R	TO-252	G	D	S	Tape Reel	
2N80L-TND-R	2N80G-TND-R	TO-252D	G	D	S	Tape Reel	

Note: Pin Assignment: G: Gate D: Drain S: Source



- (1) T: Tube, R: Tape Reel
- (2) TA3: TO-220, TF1: TO-220F1, TF2: TO-220F2,

TO-220

TO-220F1

TO-251

TO-220F2

TO-252D

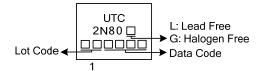
TF3: TO-220F, TM3: TO-251, TN3: TO-252

TND: TO-252D

(3) L: Lead Free, G: Halogen Free and Lead Free

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■ MARKING



■ ABSOLUTE MAXIMUM RATINGS (T_C=25°C, unless otherwise specified)

PARAMETER		SYMBOL	RATINGS	UNIT	
Drain-Source Voltage		V_{DSS}	800	V	
Gate-Source Voltage		V_{GSS}	±30	V	
Avalanche Current (Note 2)		I_{AR}	2.4	Α	
Drain Current	Continuous	Ι _D	2.4	Α	
	Pulsed (Note 2)	I _{DM}	9.6	Α	
	Single Pulsed (Note 3)	E _{AS}	180	mJ	
Avalanche Energy	Repetitive (Note 2)	E _{AR}	8.5	mJ	
Peak Diode Recovery dv/dt (Note 4)		dv/dt	4.0	V/ns	
Power Dissipation	TO-220	P _D	85		
	TO-220F/TO-220F1 TO-220F2		24	W	
	TO-251/TO-252 TO-252D		43		
Junction Temperature		TJ	+150	°C	
Storage Temperature		T_{STG}	-55 ~ + 150	°C	

Notes: 1. Absolute maximum ratings are those values beyond which the device could be permanently damaged.

Absolute maximum ratings are stress ratings only and functional device operation is not implied.

- 2. Repetitive Rating: Pulse width limited by maximum junction temperature
- 3. L = 59mH, I_{AS} = 2.4A, V_{DD} = 50V, R_{G} = 25 Ω , Starting T_{J} = 25°C
- 4. $I_{SD} \le 2.4 A$, di/dt $\le 200 A/\mu s$, $V_{DD} \le BV_{DSS}$, Starting $T_J = 25 ^{\circ}C$

■ THERMAL DATA

PARAMETER		SYMBOL	RATINGS	UNIT	
Junction to Ambient	TO-220/ TO-220F TO-220F1/TO-220F2	0	62.5	°C/\\	
	TO-251/TO-252 TO-252D	$ heta_{JA}$	110	°C/W	
Junction to Case	TO-220	$\theta_{ extsf{JC}}$	1.47	°C/W	
	TO-220F/TO-220F1 TO-220F2		5.2		
	TO-251/TO-252 TO-252D		2.85		

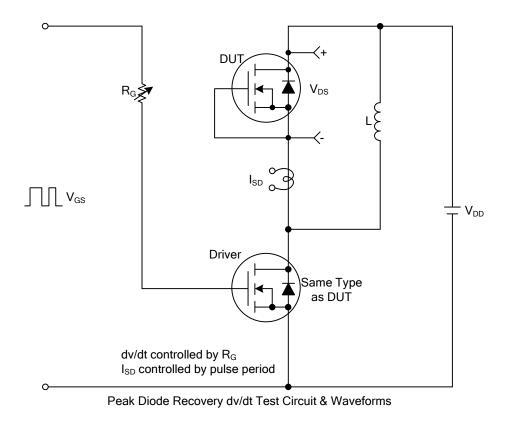
■ **ELECTRICAL CHARACTERISTICS** (T_C=25°C, unless otherwise specified)

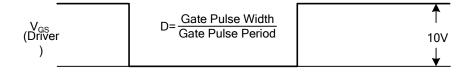
PARAMETER		SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
OFF CHARACTERISTICS							
Drain-Source Breakdown Voltage		BV _{DSS}	I _D =250μA, V _{GS} =0V	800			V
Breakdown Voltage Temperature Coefficient		△BV _{DSS} /△T _J	Reference to 25°C, I _D =250µA		0.9		V/°C
Drain-Source Leakage Current		I _{DSS}	V _{DS} =800V, V _{GS} =0V V _{DS} =640V, T _C =125°C			10 100	μΑ
Gate- Source Leakage Current	everse	I _{GSS}	V _{GS} =+30V, V _{DS} =0V V _{GS} =-30V, V _{DS} =0V			+100	nA nA
ON CHARACTERISTICS			1 00 11 7 20 1	1	ı		
Gate Threshold Voltage		$V_{GS(TH)}$	$V_{DS}=V_{GS}$, $I_{D}=250\mu A$	3.0		5.0	V
Static Drain-Source On-State Resist	tance	R _{DS(ON)}	V _{GS} =10V, I _D =1.2A		4.8	6.3	Ω
Forward Transconductance (Note 1))	9 FS	V _{DS} =50V, I _D =1.2A		2.65		S
DYNAMIC PARAMETERS						•	
Input Capacitance	Input Capacitance		\\ 0\\ \\ 0\\		550	650	pF
Output Capacitance		C _{ISS}	V _{GS} =0V, V _{DS} =25V,		45	60	pF
Reverse Transfer Capacitance		C _{RSS}	f=1.0MHz		7	9	pF
SWITCHING PARAMETERS							
Turn-ON Delay Time		t _{D(ON)}	V_{GS} =10V V_{DD} =30V, I_{D} =0.5A, R_{G} =25 Ω		50		ns
Rise Time		t _R			60		ns
Turn-OFF Delay Time		t _{D(OFF)}	(Note 1,2)		80		ns
Fall-Time		t _F	(Note 1,2)		40		ns
Total Gate Charge		Q_{G}	V _{GS} =10V, V _{DS} =50V,		18	28	nC
Gate to Source Charge		Q_{GS}	I _D =1.3A, I _G =100μA (Note 1,2)		6		nC
Gate to Drain Charge		Q_{GD}			5		nC
SOURCE- DRAIN DIODE RATINGS	S AND CHA	ARACTERISTIC	S		_	_	_
Maximum Continuous Drain-Source Forward Current	Diode	Is				2.4	Α
Maximum Pulsed Drain-Source Dioc Forward Current	de	I _{SM}				9.6	Α
Drain-Source Diode Forward Voltage		V_{SD}	I _S =2.4A, V _{GS} =0V			1.4	V
Reverse Recovery Time (Note 1)		t _{RR}	I _S =2.4A, V _{GS} =0V,		480		ns
Reverse Recovery Charge (Note 1)		Q_{RR}	dI _F /dt=100A/μs		2.0		μC

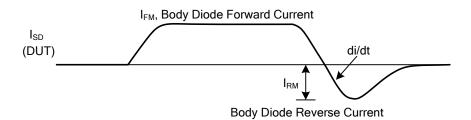
Notes: 1. Pulse Test: Pulse width ≤ 300µs, Duty cycle ≤ 2%

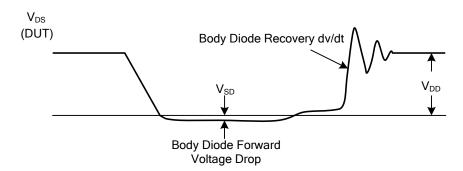
^{2.} Essentially independent of operating temperature

■ TEST CIRCUITS AND WAVEFORMS

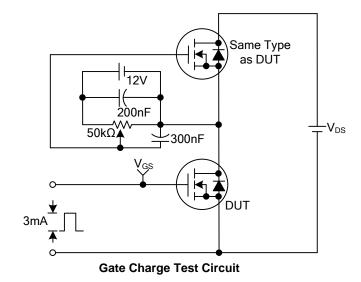


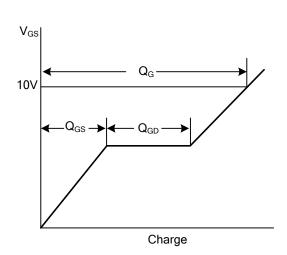




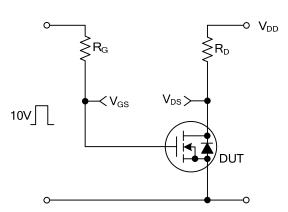


■ TEST CIRCUITS AND WAVEFORMS(Cont.)

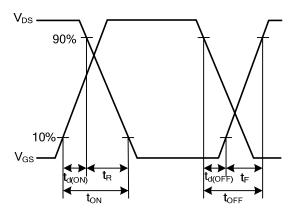




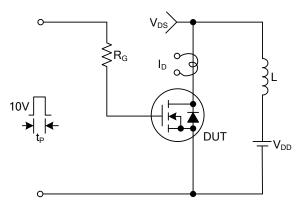
Gate Charge Waveforms



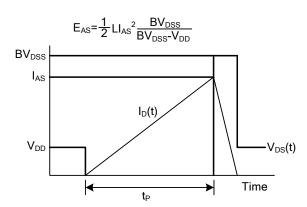
Resistive Switching Test Circuit



Resistive Switching Waveforms

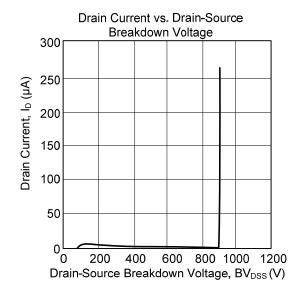


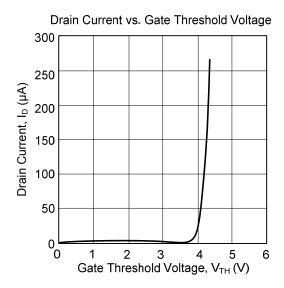
Unclamped Inductive Switching Test Circuit

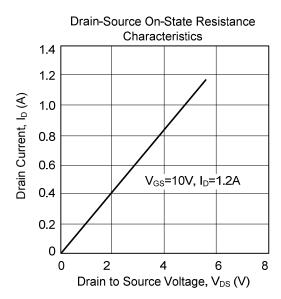


Unclamped Inductive Switching Waveforms

TYPICAL CHARACTERISTICS







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